MARKED-UP VERSION OF ENGLISH TRANSLATION OF INTERNATIONAL APPLICATION AS ORIGINALLY FILED

DESCRIPTION

HIGH FREQUENCY COMPOSITE COMPONENTPART

BACKGROUND OF THE INVENTION

1. Technical Field of the Invention

[0001]	——The p	resent inv	ention	relates	to a 1	high-fr	equency
composite <u>c</u>	component,	part and	more pa	articulaı	cly <u>,</u> to	a hig	h-
frequency o	composite	component	for u	se part u s	sable :	in a pl	urality
of differer	nt mobile	communica	tion s	ystems.			

2. Description of the RelatedBackground Art

_____Presently, in Europe, as a mobile communication device, a dual-band portable telephone <u>has been proposed</u> which can <u>operatebe operated</u> in a plurality of frequency bands, for example, in the DCS system using a 1.8 GHz band and the GSM system using a 900 MHz band <u>is proposed</u>.

Fig. 18 shows a <u>portion part</u> of the structure of a general dual-band portable telephone <u>which includes</u> and the part is composed of an antenna 1, a diplexer 2, and two signal paths of a DCS system 3 (1.8 GHz band) and a GSM system 4 (900 MHz band).

[0004] ——The diplexer 2 selects a transmission signal from the DCS system 3 or the GSM system 4 in transmission and selects a reception signal to the DCS system 3 or the GSM system 4 in

reception. The DCS system 3 <u>includes a is composed of a high-frequency</u> switch 3a for separating a transmission portion Txd and a reception portion Rxd and a filter 3b for <u>allowingmaking</u> the fundamental frequency of the DCS system <u>to pass through and for attenuating the second and third harmonics. In the same mannerway</u>, the GSM system 4 <u>is also includes composed of a high-frequency</u> switch 4a for separating a transmission portion Txg and a reception portion Rxg and a filter 4b for <u>allowingmaking</u> the fundamental frequency of the GSM system <u>to pass through and for attenuating the third harmonics</u>.

[0005] In Now, in recent years, a balanced-type (balanced-output type) high-frequency composite componentpart having two signal terminals in the reception portion has been is proposed and, in such a balanced type, the impedance matching to an LNA low-noise amplifier (LNA) is required.

Publication No. 2003-142981 (Patent Document 1), as shown in Fig. 19, it is disclosed that an inductor 6 is disposed in parallel between the balanced output terminals Rx of a bandpass filter defined by a made up of a balanced-output type surface acoustic wave filter. However, it is difficult different to set a desired impedance (complex impedance, in particular). According to the knowledge of the present inventor, in order to lower the impedance, it is required to insert a capacitor must be inserted in series to each of the balanced output terminals, and, to increase the impedance, it is required to insert one more

inductor <u>must be inserted</u> in parallel between the balanced output terminals in addition to the above-described capacitors. However, when capacitors and inductors as separate <u>componentsparts</u> are added between such a high-frequency composite <u>componentpart</u> and an LNA, the number of <u>componentsparts</u> and the mounting area increase <u>which increases the size ofto result in upsizing</u> the equipment, and the matching between the bandpass filter 5 and the LNA becomes more complicated.

SUMMARY OF THE INVENTION

[0007] To overcome the problems described above, preferred embodimentsPatent Document 1: Japanese Unexamined Patent

Application Publication No. 2003-142981

Disclosure of Invention

Accordingly, it is an object of the present invention to provide a high-frequency composite component part in which a desired impedance is can be easily set in the high-frequency composite component part itself, no matching adjustment to an LNA is required, the number of components parts is reduced, and the overall size is reduced reduction in size can be made.

Furthermore, preferred embodiments it is another object of the present invention to further provide a high-frequency composite component part in which interference between the elements is prevented, and in which shows excellent characteristics are achieved.

[0009] A In order to attain the above objects, a highfrequency composite componentpart according to a preferred embodiment of the present invention includes comprises a switch for selectively switching a signal path between an antenna terminal and a transmission-side input terminal and a signal path between the antenna terminal and a reception-side balanced output terminal, + an LC filter having an inductor and capacitors disposed between the antenna terminal and the transmission-side input terminal, + a surface acoustic wave filter disposed between the switch and the reception-side balanced output terminal, + and a matching element having an inductor and capacitors disposed between the surface acoustic wave filter and the reception-side balanced output terminal. In the high-frequency composite componentpart, the switch, the LC filter, the surface acoustic wave filter, and the matching element are integrated in an integrated block having a plurality of laminated dielectric layers - laminated.

______In the high-frequency composite componentpart according to this preferred embodiment of the present invention, since a matching element having an inductor and capacitors is disposedcontained between a surface acoustic wave filter and a reception-side balanced output terminal, it is becomes possible to freely set the impedance of the reception-side balanced output terminal by an appropriate combination of the inductor and the capacitors. Moreover, since the inductor and the capacitors are integrated in a laminated block with other circuit components, as

compared to parts, in comparison with the case—where the inductor and the capacitors are discretely arranged on a printed-circuit board, the mounting area on the printed-circuit board is can be reduced, and also the distance between the surface acoustic wave filter and the matching element is minimized, and the loss between the filter and the matching element is can be suppressed to improve high-frequency characteristics.

[0011] An Now, an important considerationthing when the switch, the LC filter, the surface acoustic wave filter, and the matching element are integrated in a laminated block having a plurality of dielectric layers laminated is to arrange the components such that make arrangement so that the interference between the matching element and the LC filter is can be prevented. In particular, regarding the inductance of the matching element, a high Q value and stability are required.

[0012] In Then, in a high-frequency composite componentpart according to this preferred embodiment of the present invention, it is desirable that the inductor of the matching element be disposedformed in a first area of the laminated block, and that the inductor and the capacitors of the LC filter be disposedformed in a second area different from the first area as viewedwhen seen from the top.

[0013] ——In the same <u>mannerway</u>, it is desirable that the inductor of the matching element be <u>disposed</u> mounted on the surface of the laminated block and that the inductor and <u>the</u> capacitors of the LC filter be disposed contained inside the

laminated block. Furthermore, it is desirable that a ground electrode be disposed between the inductor of the matching element and the inductor and the capacitors of the LC filter.

Alternatively, Or it is desirable that a shunt capacitor of the capacitors of the LC filter be disposed formed in the vicinity of the lowest layer of the laminated block.

_____The inductor and the capacitors capacitances of the matching element are disposed formed on the surface of the laminated block, and the inductor of the matching element may be disposed so as to be directly next to the capacitors of the matching element with nonot through any other elements disposed therebetween.

Furthermore, the surface acoustic wave filter may be a balanced-type surface acoustic wave filter having balanced output ports or the surface acoustic wave filter may be an unbalanced-type surface acoustic wave filter having unbalanced output ports. When the surface acoustic wave filter is of—a balanced—type_filter, the inductor of the matching element is connected in parallel between the balanced output ports, and the capacitors of the matching element are connected in series to the balanced output ports. Furthermore, when the surface acoustic wave filter is of—an unbalanced—type_filter, the inductor and the capacitors of the matching element function as a balun.

[0016] _____Moreover, a high-frequency composite componentpart according to a preferred embodiment of the present invention is can be constituted as—a high-frequency composite componentpart of

a dual-band type in which signals in two different frequency bands can be processed. In such a high-frequency composite componentpart of a dual-band type, a diplexer for branching a signal path for a first frequency band and a signal path for a second frequency band different from the first frequency band is provided contained at the rear stage of the antenna terminal. In+ in the signal path for a first frequency band, a first switch for selectively switching a signal path between the antenna terminal and a first transmission-side input terminal and a signal path between the antenna terminal and a first reception-side balanced output terminal, a first LC filter having an inductor and capacitors disposed between the first switch and the first transmission-side input terminal, a first surface acoustic wave filter disposed between the first switch and the first receptionside balanced output terminal, and a first matching element having an inductor and capacitors disposed between the first surface acoustic wave filter and the first reception-side balanced output terminal are provided. Incontained; in the signal path for a second frequency band, a second switch for selectively switching a signal path between the antenna terminal and a second transmission-side input terminal and a signal path between the antenna terminal and a second reception-side balanced output terminal, a second LC filter having inductors and capacitors disposed between the second switch and the second transmission-side input terminal, a second surface acoustic wave filter disposed between the second switch and the second

reception-side balanced output terminal, and a second matching element having an inductor and capacitors disposed between the second surface acoustic wave filter and the second reception-side balanced output terminal are provided. The contained; and the diplexer, the first and second switches, the first and second LC filters, the first and second surface acoustic wave filters, and the first and second matching elements are integrated in a laminated block having a plurality of laminated dielectric layers laminated.

[0017] A — Moreover, a high-frequency composite componentpart according to another preferred embodiment of the present invention is can be constituted as a high-frequency composite componentpart of a triple-band type in which signals in three different frequency bands can be processed. In such a highfrequency composite componentpart of a triple-band type, a diplexer for branching a signal path for a first frequency band and a signal path for a second frequency band different from the first frequency band is provided at the rear stage of the antenna terminal. In; in the signal path for a first frequency band, a first switch for selectively switching a signal path between the antenna terminal and a first transmission-side input terminal and a signal path between the antenna terminal and a first receptionside balanced output terminal, a first LC filter having an inductor and capacitors disposed between the first switch and the first transmission-side input terminal, a first surface acoustic wave filter disposed between the first switch and the first

reception-side balanced output terminal, and a first matching element having an inductor and capacitors disposed between the first surface acoustic wave filter and the first reception-side balanced output terminal are provided. Incontained; in the signal path for a second frequency band, a second switch for selectively switching a signal path between the antenna terminal and a second transmission-side input terminal and a signal path between the antenna terminal and second and third reception-side balanced output terminals, a second LC filter having inductors and capacitors disposed between the second switch and the second transmission-side input terminal, a duplexer branching a signal path disposed between the second switch and the second receptionside balanced output terminal and a signal path disposed between the second switch and the third reception-side balanced output terminal, a second surface acoustic wave filter disposed between the duplexer and the second reception-side balanced output terminal, a second matching element having an inductor and capacitors disposed between the second surface acoustic wave filter and the second reception-side balanced output terminal, a third surface acoustic wave filter disposed between the duplexer and the third reception-side balanced output terminal, and a third matching element having an inductor and capacitors disposed between the third surface acoustic wave filter and the third reception-side balanced output terminal are provided. The contained; and the diplexer, the first and second switches, the first and second LC filters, the first, second, and third surface

acoustic wave filters, and the first, second, and third matching elements are integrated in a laminated block having a plurality of laminated dielectric layers.

[0018] Other features, elements, steps, characteristics and advantages of the present invention will become more apparent from the following detailed description of preferred embodiments of the present invention with reference to the attached drawings laminated.

Brief Description of the Drawings BRIEF DESCRIPTION OF THE DRAWINGS

[0019] ——Fig. 1 is a block diagram showing the basic
structure of a first <u>preferred</u> embodiment of a high-frequency
composite componentpart according to the present invention.
[0020] ——Fig. 2 is an equivalent circuit diagram of the
first <pre>preferred_embodiment.</pre>
[0021]Fig. 3 is a block diagram showing the basic
structure of a second <u>preferred</u> embodiment of a high-frequency
composite componentpart of the present invention.
[0022] ——Fig. 4 is an equivalent circuit diagram of the
second <u>preferred</u> embodiment.
[0023] ——Fig. 5 is a schematic illustration showing the
shape of electrodes provided formed on each sheet layer (first to
eighth layers from the $\underline{\text{bottom}}\underline{\text{lower}}$) of a ceramic multilayer
substrate of the second <u>preferred</u> embodiment.
[0024] ——Fig. 6 is a schematic illustration showing the

shape of electrodes provided formed on each sheet layer (ninth to fifteenth layers from the bottomlower) of a ceramic multilayer substrate of the second preferred embodiment. [0025] ——Fig. 7 is a schematic illustration showing the shape of electrodes provided formed on each sheet layer (sixteenth and seventeenth layers from the bottom lower) of a ceramic multilayer substrate of the second preferred embodiment. [0026] ——Fig. 8 is a top view showing the mounting state of each circuit element on the surface of the ceramic multilayer substrate of the second preferred embodiment. [0027] ——Fig. 9 is a block diagram showing the basic structure of a third preferred embodiment of a high-frequency composite componentpart according to the present invention. [0028] ——Fig. 10 is an equivalent circuit diagram of the third preferred embodiment. [0029] ——Fig. 11 is an equivalent circuit diagram of a fourth preferred embodiment of a high-frequency composite componentpart according to the present invention. [0030] ——Fig. 12 is a schematic illustration showing the shape of electrodes provided formed on each sheet layer (first to eighth layers from the bottomlower) of a ceramic multilayer substrate of the fourth preferred embodiment. [0031] ——Fig. 13 is a schematic illustration showing the shape of electrodes provided formed on each sheet layer (ninth to fifteenth layers from the bottomlower) of a ceramic multilayer substrate of the fourth preferred embodiment.

[0032] ——Fig. 14 is a schematic illustration showing the shape of electrodes provided formed on each sheet layer (sixteenth and seventeenth layers from the bottom lower) of a ceramic multilayer substrate of the fourth preferred embodiment. [0033] ——Fig. 15 is a top view showing the mounting state of each circuit element on the surface of the ceramic multilayer substrate of the fourth preferred embodiment. [0034] ——Fig. 16 is an equivalent circuit diagram of a fifth preferred embodiment of a high-frequency composite componentpart according to the present invention. [0035] ——Fig. 17 is an equivalent circuit diagram of a sixth preferred embodiment of a high-frequency composite componentpart according to the present invention. [0036] ——Fig. 18 is a block diagram showing a switching circuit of a related dual-band portable telephone. [0037] ——Fig. 19 is a block diagram showing the outline of the structure of a related bandpass filter.

DETAILED DESCRIPTION OF PREFERRED EMBODIMENTS Best Mode for Carrying Out the Invention

_____Hereinafter, the <u>preferred</u> embodiments of a high-frequency composite <u>component</u> according to the present invention are described with reference to the accompanied drawings.

----First Preferred Embodiment (embodiment (see Figs. 1 and 2)

In a high-frequency composite component part of a single-band type according to the of the present first preferred embodiment, as the characteristic structure is shown in a block diagram of Fig. 1, an inductor L is connected in parallel between the balanced output portion of a balanced-typed surface acoustic wave filter SAW and the reception-side balanced output terminal Rx, and capacitors C1 and C2 are connected in series, respectively.

[0042] ——In the matching element 13, as described above, the inductor L is connected in parallel and the capacitors C1 and

C2 are connected in series, respectively, between the balanced output portion of the surface acoustic wave filter SAW and the reception-side balanced output terminal Rx.

_____Furthermore, in the present_first preferred embodiment, the above-described high-frequency switch 11, LC filter 12, surface acoustic wave filter SAW, and matching element 13 are integrated united in a laminated block in which a plurality of dielectric layers are laminated.

The high-frequency composite component according to the part of the present first preferred embodiment, which is of a single-band type, is included in high-frequency composite componentsparts of second and third preferred embodiments of a dual-band type and a high-frequency composite componentpart of a fourth preferred embodiment of a triple-band type as a component thereof.part of them. Accordingly, the more detailed structure and operation of the present first preferred embodiment are disclosed with reference tomade clear through the second, third, fourth, fifth, and sixth preferred embodiments to be described later.

Second Preferred Embodiment (embodiment (see Figs. 3 to 8)

[0045] — A high-frequency composite component according to the part of the present second preferred embodiment is a high-frequency composite component part (front-end module) of a dual-band type having GSM and DCS systems, as its characteristic structure is shown in a block diagram in Fig. 3. Inductors Lg

and Ld are connected in parallel between the balanced output portions of balanced-type surface acoustic wave filters SAWg and SAWd and reception-side balanced output terminals Rxg and Rxd, and capacitors Clg and C2g, and Cld and C2d are connected in series, respectively.

switches a signal path between the antenna terminal ANT and a first transmission-side input terminal Txg and a signal path between the antenna terminal ANT and a first reception-side balanced output terminal Rxg. The first LC filter 12G is disposed between the first high-frequency switch 11G and the first transmission-side input terminal Txg. The first surface acoustic wave filter SAWg is disposed between the first high-frequency switch 11G and the frequency switch 11G and the first reception-side balanced output terminal Rxg.

is connected in parallel on the side of the first surface acoustic wave filter SAWg, and the capacitors C1g and C2g are connected in series between the inductor Lg and the receptionside balanced output terminal Rxg, respectively.

______The second high-frequency switch 11D selectively switches a signal path between the antenna terminal ANT and a second transmission-side input terminal Txd and a signal path between the antenna terminal ANT and a second reception-side balanced output terminal Rxd. The second LC filter 12D is disposed between the second high-frequency switch 11D and the second transmission-side input terminal Txd. The second surface acoustic wave filter SAWd is disposed between the second high-frequency switch 11D and the second reception-side balanced output terminal Rxd.

[0050] ——In the second matching element 13D, an inductor Ld is connected in parallel on the side of the second surface acoustic wave filter SAWd, and the capacitors C1d and C2d are connected in series between the inductor Ld and the receptionside balanced output terminal Rxd, respectively.

______The diplexer 20 selects a transmission signal from the DCS system or the GSM system <u>during in the case of</u> transmission and selects a reception signal to the DCS system or the GSM system <u>during in the case of</u> reception. The antenna terminal ANT is connected to a first port P11 of the diplexer 20, the first port P31g of the first high-frequency switch 11G is

connected to a second port P12, and the first port P31d of the second high-frequency switch 11D is connected to a third port P13.

[0052] ——In the GSM system, a first port P21g of the first LC filter 12G is connected to a second port P32g of the first high-frequency switch 11G, and the first surface acoustic wave filter SAWg is connected to a third port P33g. The first transmission-side input terminal Txg is connected to a second port P22g of the first LC filter 12G.

[0053] ——In the DCS system, a first port P21d of the second LC filter 12D is connected to a second port P32d of the second high-frequency switch 11D, and the second surface acoustic wave filter SAWd is connected to a third port P33d. The transmission-side second input terminal Txd is connected to a second port P22d of the second LC filter 12D.

_____The first high-frequency switch 11G <u>includes is</u>

composed of diodes GD1 and GD2 as switching elements, inductors

GSL1 and GSL2, capacitors GC5 and GC6, and a resistor RG. The diode GD1 is connected between the first port P31g and the second port P32g such so—that the anode is may be—on the side of the first port P31g, and the cathode is grounded through the inductor GSL1. The cathode of the diode GD2 is connected to the first port P31g through the inductor GSL2, and the anode is grounded through the capacitor GC5. A control terminal Vc1 is connected to the connection point between the diode GD2 and the capacitor GC5 through the resistor RG. Furthermore, the connection point between the cathode of the diode GD2 and the third port P33g is grounded through the capacitor GC6.

[0056] ——The second high-frequency switch 11D includes is composed of diodes DD1 and DD2 as switching elements, inductors DSL1, DSL2, and DSLt, capacitors DC6, DC7, and DCt1, and a resistor RD. The diode DD1 is connected between the first port P31d and the second port P32d such so—that the anode is may be—on the side of the first port P31d, and the cathode is grounded through the inductor DSL1. Furthermore, a series circuit of the capacitor DCt1 and the inductor DSLt is connected in parallel to the diode DD1 between the first port P31d and the second port The cathode of the diode DD2 is connected to the first P32d. port P31d through the inductor DSL2, and the anode is grounded through the capacitor DC5. A control terminal Vc2 is connected to the connection point between the diode DD2 and the capacitor DC5 through the resistor RD. Furthermore, the cathode of the diode DD2 is connected to the third port P33d through the

capacitor DC6, and the connection point between the cathode and the capacitor DC6 is grounded through the capacitor DC7.

[0057] ——In the first LC filter 12G, a parallel circuit of an inductor GLt1 and a capacitor GCc1 is connected between the first port P21g and the second port P22g. Both ends of the inductor GLt1 are grounded through capacitors GCu1 and GCu2,

respectively.

______In the second LC filter 12D, a parallel circuit of an inductor DLt1 and a capacitor DCc1 and a parallel circuit of an inductor DLt2 and a capacitor DCc2 are connected in series between the first port P21d and the second port P22d. Both ends of the inductor DLt1 are grounded through capacitors DCu1 and DCc2, respectively.

Figs. 5 to 7 show capacitor electrodes and, strip line electrodes, etc., formed by screen printing or other suitable method,, etc., on each sheet layer definingconstituting a ceramic multilayer substrate of a high-frequency composite component according to the part of the present second preferred embodiment. The ceramic multilayer substrate is formed in such a way—that first to seventeenth sheet layers 61a to 61q made of ceramics having barium oxide, aluminum oxide, and silica as main components are laminated in order from the bottomlower and sintered at a temperature of about 1000°C or less.

[0060] ——Various terminal electrodes for external connection are <u>provided</u> on the first sheet layer 61a. A ground electrode G1 is provided formed on the second sheet layer

61b, the electrodes for the capacitors GCu1, GCu2, Ct2, and GC5 are providedformed on the third sheet layer 61c to defineform capacitances together with the ground electrode G1. A ground electrode G2 is providedformed on the fourth sheet layer 61d, and the electrodes for the capacitors DCu1 and DCu2 are providedformed on the fifth sheet layer 61e to defineform capacitances with the ground electrode G2.

______The inductors Lt1, Lt2, DLt1, DLt2, GLt1, DSL1, and DSL2 are definedformed by stripline electrodes on the seventh and ninth sheet layers 61g and 61i and these—are connected by via holes. Moreover, the inductors Lt1, Lt2, DLt1, DLt2, GLt1, and DSL2 are definedformed by stripline electrodes on the eleventh sheet layer 61k and those—are connected to the same electrodes on the lower layers by via holes.

_____The electrodes of the capacitors Ct1 and DCc1 are providedformed on the twelve sheet layer 611, and the electrodes of the capacitors Ct1, Cc1, DCt1, and GCc1 and the ground electrode G3 are provided.formed. The electrodes of the capacitors Cc1, DCt1, GCc1, and DC5 are providedformed on the fourteenth sheet layer 61n. The electrodes of the capacitors Cc2 and DCt1 and the ground electrode G4 are providedformed on the fifteenth sheet layer 61o.

[0063] ——As shown in Fig. 8, various connection terminal electrodes are <u>provided</u> on the surface of the seventeenth sheet layer 61q <u>defining</u> defining the surface of the ceramic multilayer substrate 50. Then, on the surface, the first and

second surface acoustic wave filters SAWg and SAWd and the diodes GD1, GD2, DD1, and DD2 are mounted, and the inductor Lg and the capacitors C1g and C2g definingconstituting the first matching element 13G and the inductor Ld and the capacitors C1d and C2d definingconstituting the second matching element 13D are mounted. Moreover, the resistors RG and RD and the inductors DSL1, DSLt, and GSL1 are mounted on the surface of the ceramic multilayer substrate 50.

______Here, the operation of the high-frequency composite componentpart having the circuit structure shown in Fig. 4 is described. First, when a transmission signal of the DCS system (1.8 MHz band) is sent, in the second high-frequency switch 11D, the transmission signal of the DCS system passes through the second LC filter 12D, the second high-frequency switch 11D, and the diplexer 20 and is transmitted from the antenna terminal ANT connected to the first port P11 of the diplexer 20 in—such a away—that, for example, about 3 V is applied to the control terminal Vc2 to turn on the diodes DD1 and DD2.

[0065] —At this time, in the first high-frequency switch

11G of the GSM system, the transmission signal of the GSM system

is made not to be transmitted in such a way that, for example, 0

V is applied to the control terminal Vc1 to turn off the diode

GD1. Furthermore, the transmission signal of the DCS system

doesis made not to enter the first transmission-side input

terminal Txg and the first reception-side balanced output

terminal Rxg of the GSM system due to the connection of the diplexer 20. Moreover, the second and third harmonics of the DCS system are attenuated in the second LC filter 12D of the DCS system.

[0066] —Next, when a transmission signal of the GSM system (900 MHz band) is sent, in the first high-frequency switch 11G, the transmission signal of the GSM system passes through the first LC filter 12G, the first high-frequency switch 11G, and the diplexer 20 and is transmitted from the antenna terminal ANT connected to the first port P11 of the diplexer 20 in—such a way that, for example, about 3 V is applied to the control terminal Vc1 to turn on the diodes GD1 and GD2.

_____At this time, in the second high-frequency switch 11D of the DCS system, the transmission signal is made_not to be transmitted in_such a way that, for example, 0 V is applied to the control terminal Vc2 to turn off the diode DD1. Furthermore, the transmission signal of the GSM system does is made not to enter the second transmission-side input terminal Txd and the second reception-side balanced output terminal Rxd of the DCS system due to the connection of the duplexer 20.

[0068] — Moreover, the second harmonic of the GSM system is attenuated in the low-pass filter made up of the capacitor Ct1, the inductor Lt1, and the shunt capacitor Cu1 of the diplexer 20 and the third harmonic of the GSM system is attenuated in the first LC filter 12G of the GSM system.

[0069] ——Next, when reception signals of the DCS system and

the GSM system are received, in the second high-frequency switch 11D of the DCS system, a reception signal of the DCS system doesis made not toenter the second transmission-side input terminal Txd suchin such a way that, for example, 0 V is applied to the control terminal Vc2 to turn off the diodes DD1 and DD2, and, in the first high-frequency switch 11G of the GSM system, a reception signal of the GSM system does is made not to enter the first transmission-side input terminal Txg of the GSM system in such a way that 0 V is applied to the control terminal Vc1 to turn off the diodes GD1 and GD2. Then, the signals input from the antenna terminal ANT are output to the reception-side balanced output terminal Rxd of the DCS system and the receptionside balanced output terminal Rxq of the GSM system, respectively. [0070] ——Furthermore, the reception signal of the DCS system doesis made not toenter the GSM system and the reception signal of the GSM system doesis made not toenter the DCS system due to the connection of the diplexer 20.

In the high-frequency composite component according to the part of the present second preferred embodiment, since the matching elements 13G and 13D including the inductors Lg and Ld and the capacitors C1g, C2g, C1d, and C2d are disposed contained between the surface acoustic wave filters SAWg and SAWd and the reception-side balanced output terminals Rxg and Rxd, it isbecomes possible to freely to set the impedance of the reception-side balanced output terminals Rxg and Rxd by appropriate combinations of the inductors and capacitors.

Furthermore, since the inductors Lg and Ld and the capacitors C1g, C2g, C1d, and C2d are integrated in the ceramic laminated substrate together with the other circuit components, as parts, in comparison to when with the case where such inductors and capacitors are discretely disposed on a printed circuit board, the mounting surface on the printed substrate is can be reduced and simultaneously the distance between the surface acoustic wave filters SAWg and SAWd and the matching elements 13G and 13D is minimized so as to suppressand the loss between the filters SAWg and SAWd and the matching elements 13G and 13D and can be suppressed to improve the high-frequency characteristics.

Furthermore, since the inductors Lg and Ld of the matching elements 13G and 13D are arrangedformed so as not to overlap with the inductors and capacitors of the LC filters 12G and 12D in the ceramic laminated substrate as when seen from the top, the isolation between the transmission and reception lines is secured and the mixture of a signal is can be prevented. Since the inductors Lg and Ld of the matching elements 13G and 13D are mounted on the surface of the ceramic laminated substrate, the same effect is can be attained by the inductors and capacitors of the LC filters 12G and 12D being disposed contained inside the ceramic laminated substrate.

[0074] — Moreover, in the present <u>preferred</u> embodiment, the capacitors Clg, C2g, Cld, and C2d of the matching elements 13G and 13D are arrangedformed so as not to overlap with the

inductors and capacitors of the LC filters 12G and 12D <u>as when</u> seen from the top. In this <u>mannerway</u>, the mixture of a signal between the transmission and reception lines <u>is can be</u> more effectively prevented.

[0075] ——Furthermore, since the ground electrode G4 is disposed between the inductors Lq and Ld of the matching elements 13G and 13D and the inductors and capacitors of the LC filters 12G and 12D, the interference between these components is them can be effectively prevented. In addition, since Also by the fact that the capacitors of the LC filters 12G and 12D, that is, the shunt capacitors GCu1, GCu2, DCu1, and DCu2, in particular, are disposed formed in the vicinity of the lower layer of the ceramic laminated substrate, the same effect is can be obtained. Since the inductors Lg and Ld and the capacitors Clg, Cg2, Cld, and C2d of the matching elements 13G and 13D are disposed formed on the surface of the ceramic laminated substrate, and since also the disposition of the inductors Lq and Ld of the matching elements 13G and 13D are arrangedso as to be next to the capacitors Clg, C2g, Cld, and C2d of the matching elements 13G and 13D with no not through other elements disposed therebetween, can prevent mutual interference is effectively preventedin the same way.

[0076] — Moreover, in the present <u>preferred</u> embodiment, the ground electrode G4 is also disposed between the capacitors C1g, C2g, C1d, and C2d and the inductors capacitors of the LC filters 12G and 12D. Thus, the interference between these components the

both can be effectively prevented.

Furthermore, as shown in Fig. 8, on the surface of the ceramic multilayer substrate, the surface mounting components definingparts constituting the matching elements 13G and 13D are disposed so as to be next to the surface mounting components definingparts constituting the high-frequency switches 11G and 11D and the diplexer 20 through the surface acoustic wave filters SAWg and SAWd. With such an arrangement when such a disposition is made, the interference between the matching elements 13G and 13D and the other elements is can be more effectively suppressed.

Third Preferred Embodiment (embodiment (see Figs. 9 and 10)

[0078] — A high-frequency composite component according to apart of the present third preferred embodiment is a dual-band type high-frequency composite component part of a dual-band type having GSM and DCS systems similar to in the same way as in the second preferred embodiment. As, as its characteristic structure is shown in a block diagram in Fig. 9, and the capacitors C1g and C2g, and Cd and C2d are connected in series to the balanced output portions of the balanced-type surface acoustic wave filters SAWg and SAWd, and the inductors Lg and Ld are connected in parallel to the reception-side balanced output terminals Rxg and RXd.

[0079] — Thus, the impedance of the first and second reception-side balanced output terminals Rxg and Rxd can be freely set and the impedance can be increased, in particular,

<u>such</u> in such a way that the capacitors C1g and C2g and the capacitors C1d and C2d are connected in series to the side of the first and second surface acoustic wave filters SAWg and SAWd, and that the inductors Lg and Ld are connected in parallel to the side of the first and second reception-side balanced output terminals Rxg and Rxd, respectively.

embodiment, the circuit structure and operation, except for the first and second matching elements 13G and 13D, are the same as in the second preferred embodiment and the overlapping description is omitted.

Fourth Preferred Embodiment (embodiment (see Figs. 11 to 15)

[10081] ——A high-frequency composite component according to a part of the present fourth preferred embodiment is constituted as—a triple-band type high-frequency composite component part of a triple-band type having a GSM system and a DCS system branching off into two reception-side balanced output terminals Rxd1 and Rxd2, as shown in an equivalent circuit diagram of Fig. 11.

[10082] ——That is, the GSM system includes contains a first high-frequency switch 11G, a first LC filter 12G, a balanced-type first acoustic wave filter SAWg, and a first matching element 13G. The structure and operation of the GSM system is the same as that in the above-described second and third preferred embodiments and the overlapping description is omitted.

[0083] ____ The diplexer 20 also includes substantially the

contains the basically same structure as that in the second and third preferred embodiments and, in addition, a capacitor Cant is connected between the first port P11 and the antenna terminal ANT, and the connection point is grounded through an inductor Lant. [0084] ——The DCS system includes is composed of a second high-frequency switch 11D', a second LC filter 12D, and a second transmission-side input terminal Txd. The circuit structure of this portion is the same as that in the second and third preferred embodiments and the overlapping description is omitted. [0085] ——In the DCS system, the third port P33d of the second high-frequency switch 11D' is connected to a duplexer 14D, and the duplexer 14D branches makes the path of a reception signal branch-into a second reception-side balanced output terminal Rxd1 and a third reception-side balanced output terminal Rxd2. [0086] ——The second high-frequency switch 11D' selectively switches a signal path between the antenna terminal ANT and the second transmission-side input terminal Txd and a signal path between the antenna terminal ANT and the second and third reception-side balanced output terminals Rxd1 and Rxd2. [0087] ——The second high-frequency switch 11D' includes is composed of the diodes DD1, and DD2 as switching elements, inductors DPSL1, DSL2, and DPSLt, capacitors DC5, DC6, DPCt, and a resistor DR1. The diode DD1 is connected between the first port P31d and the second port P32d such so-that the anode ismay be on the side of the second port P32d, and the anode is grounded through the inductor DPSL1 and the capacitor DC6. The control

terminal Vc2 is connected to the connection point between the inductor DPSL1 and the capacitor DC6. Furthermore, a series circuit of the capacitor DPCt and the inductor DPSLt is connected between the first port P31d and the second port P32d so as to be parallel to the diode DD. The anode of the diode DD2 is connected to the first port P31d through the inductor DSL2, and the cathode is grounded through the capacitor DC5. The connection point between the diode DD2 and the capacitor DC5 is grounded through the DR1.

[0089] ——A second matching element 13D1 is connected to the balanced output portion of the second surface acoustic wave filter SAWd1, and a third matching element 13D2 is connected to the balanced output portion of a third surface acoustic wave filter SAWd2. In the second and third matching elements 13D1 and 13D2, in the same mannerway as in the second preferred embodiment,

the inductors Ld are connected in parallel on the side of the surface acoustic wave filters SAWd1 and SAWd2, and the capacitors C2d and C2d are connected in series between the inductors Ld and the reception-side balanced output terminals Rxd1 and Rxd2, respectively. The operation-effect is the same as in the second preferred embodiment. Moreover, the second and third matching elements 13D1 and 13D2 may be made to have the same circuit structure as inthat of the third preferred embodiment, and in this case, the same operation effect is ean be obtained as in the third preferred embodiment.

Figs. 12 to 14 show the capacitor electrodes and, stripline electrodes, etc., formed by a screen printing or other suitable method, etc., on each sheet layer defining constituting the ceramic multilayer substrate of a high-frequency composite component according to the part of the present fourth preferred embodiment.

______The inductors Lt1, Lt2, DLt1, DLt2, GLt1, GSL2, DSL2, and PSL2 are provided formed on the eight sheet layer 62h by using stripline electrodes. Inductors GSL2 and Lt1 are provided formed on the ninth sheet layer 62i by using stripline electrodes and connected to the electrodes on lower layers through via holes.

______The inductors Lt1, Lt2, DLt1, DLt2, GLt1, GSL2, DSL2, and DSL2 are providedformed on the tenth sheet layer 62j by using stripline electrodes and connected to the electrodes of the same kind on lower layers through via holes. Inductors Lt1 and GSL2 are providedformed on the eleventh sheet layer 62k using stripline electrodes and connected to the electrodes of the same kind on lower layers through via holes.

_____The inductors Lt2, DLt1, DLt2, GLt1, GSL2, and DSL2 are provided on the twelve sheet layer 621 by using stripline electrodes and connected to the electrodes of the same kind on lower layers through via holes. The electrodes of the capacitors Ct1 and DCc2 are provided formed on the thirteenth sheet layer 62m, and the electrodes of the capacitors Ct1 and Cc1 and the ground electrode G13 are provided formed on the fourteenth sheet layer 62m. The electrodes of the capacitors DC5, Ct1, Cc1, GCc1, GC5, DCu1, and DCc2 are provided formed on the fifteenth sheet layer 62o. The electrodes of the capacitors Cc2 and CCc1 and a ground electrode G14 are provided formed on the sixteenth sheet layer 62p. The electrodes of the capacitor DCc1 are provided formed on the seventeenth sheet layer 62q.

The surface of the nineteenth sheet layer 62s is the surface of the ceramic multilayer substrate 50, as is shown in Fig. 15, and various connection terminal electrodes are provided formed and the first to third surface acoustic wave filters SAWg, SAWd1, and SAWd2 and the diodes GD1, GD2, DD1, and DD2 are mounted thereon. Moreover, the inductor Lg and the capacitors C1g and C2g defining constituting the first matching element 13G and the inductor Ld and the capacitors C1d and C2d defining constituting the second and third matching elements 13D1 and 13D2 are mounted thereon.

[0096] — Moreover, on the surface of the ceramic multilayer substrate 50, the resistors RG and DR1 are mounted, the inductors Lant, DPCt, DPSLt, DSL1, and DPSL1 are mounted, and the capacitors Cant, DC7, and PC7 are mounted.

[0098] ——In particular, as shown in Fig. 15, on the surface of the ceramic multilayer substrate, the surface mounting components defining parts constituting the matching elements 13G,

13D1, and 13D2 are disposed so as to be opposite to the surface mounting components defining parts constituting the high-frequency switches 11G and 11D', the diplexer 20, and the duplexer 14D through the surface acoustic wave filters SAWg, SAWd1, and SAWd2. Such an arrangementa disposition can further suppresses the interference between the matching elements 13G, 13D1, and 13D2 and the other elements.

----Fifth Preferred Embodiment (embodiment (see Fig. 16) [0099] ——A high-frequency composite component according to apart of the present fifth preferred embodiment is is constituted so as to be of a triple-band type, as shown in an equivalent circuit of Fig. 16. The structure is basically the same as that of the fourth preferred embodiment (see Fig. 11) and the operation effect is also the same as the fourth preferred embodiment. The What is different between the fifth preferred embodiment and the fourth preferred embodiment is in that the reception-side balanced output terminals Rxd1 and Rxd2 are separated by a diode switch 15D, instead of by the duplexer 14D. The In detail, the diode switch 15D includes is composed of diodes SDD1 and SDD2 as switching elements, inductors SID1 and SID2, capacitors SC1, SC2, and SC3, and a resistor SR. A first port P51d is connected to the third port P33d of the second high-frequency switch 11D', and the other end of the capacitor SC3, one end of which is connected to the first port $P51d_{\underline{I}}$ is connected to the anode of the diode SDD2 through the

cathode of the diode SDD1 and the inductor SID2.

______The anode of the diode SDD1 is grounded through the inductor SID1 and the capacitor SC1, and a control terminal Vc3 is connected to the connection point between the inductor SID1 and the capacitor SC1. The cathode of the diode SDD2 is grounded through the capacitor SC2, and the connection point between the cathode and the capacitor SC2 is grounded through the resistor SR. The second port P52d connected to the anode of the diode SDD1 is connected to the second surface acoustic wave filter SAWd1. Furthermore, the third port P53d connected to the anode of the diode SDD2 is connected to the third surface acoustic wave filter SAWd2.

____Sixth Preferred Embodiment (embodiment (see Fig. 17)

[0102] ____A high-frequency composite component according topart of the sixth preferred embodiment is constituted so as to be of a triple-band type high-frequency composite component, as shown in Fig. 17. The structure is basically the same as that of the fourth preferred embodiment (see Fig. 11) and the operation effect is also the same as in the fourth preferred embodiment.

The difference isWhat is different is in that the surface acoustic wave filters SAWd1 and SAWd2 having unbalanced output ports are of an unbalanced type and the matching elements 13D1 and 13D2 connected to the unbalanced output ports are definedconstituted as baluns.

----Other Embodimentsembodiments

_____Moreover, the high-frequency composite componentsparts according to the present invention are not limited to the above-described embodiments, and but various modifications can be made without departing from the spirit and the scope of the invention.

embodiments, high-frequency composite <u>componentsparts</u> of a single-band type, a dual-band type, and a triple-band type were described, but the present invention can be also applied to high-frequency composite <u>componentsparts</u> of any multi-band type, such as—of a quad-band or more-band—type.

embodiments, although the LC filters 12, 12G, and 12D for attenuating higher-order harmonics are disposed between the high-frequency switches are 11, 11G, 11D, and 11D' and the transmission-side input terminals Tx, Txg, and Tsd, they may be disposed between the antenna terminal ANT (diplexer 20) and the high-frequency switch.

Industrial Applicability

[0106] ——As described above, the present invention is useful for a high-frequency composite component which can be utilized in a plurality of different mobile communication systems and, in particular, is advantageous because excellent in that a desired impedance can be easily set and no matching adjustment to

LNAs is required.

[0107] While preferred embodiments of the present invention have been described above, it is to be understood that variations and modifications will be apparent to those skilled in the art without departing the scope and spirit of the present invention.

The scope of the present invention, therefore, is to be determined solely by the following claims.